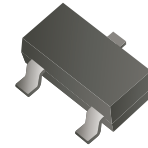


FMMT619-HF (NPN)

RoHS Device
Halogen Free



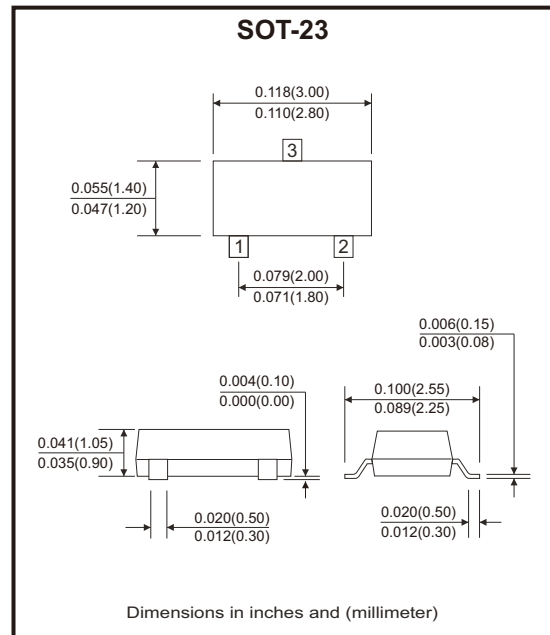
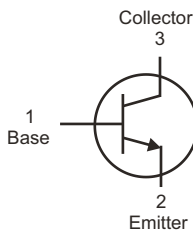
Features

- Low saturation voltage.

Mechanical Data

- Case: SOT-23, molded plastic.
- Mounting position: Any.

Circuit Diagram



Maximum Ratings (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Units
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current-continuous	I_C	2	A
Power dissipation	P_C	350	mW
Thermal resistance from junction to ambient	$R_{\theta JA}$	357	$^\circ\text{C/W}$
Maximum power dissipation (Note 1)	P_{CM}	625	mW
Thermal resistance from junction to ambient (Note 1)	$R_{\theta JA}$	200	$^\circ\text{C/W}$
Operation junction and storage temperature range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}, I_E = 0$	50			V
Collector-emitter breakdown voltage (Note 2)	$V_{(BR)CEO}$	$I_C = 10\text{mA}, I_B = 0$	50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 100\mu\text{A}, I_C = 0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB} = 40\text{V}, I_E = 0$			100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = 4\text{V}, I_C = 0$			100	nA
DC current gain (Note 2)	$h_{FE(1)}$	$V_{CE} = 2\text{V}, I_C = 10\text{mA}$	200			
	$h_{FE(2)}$	$V_{CE} = 2\text{V}, I_C = 0.2\text{A}$	300			
	$h_{FE(3)}$	$V_{CE} = 2\text{V}, I_C = 1\text{A}$	200			
	$h_{FE(4)}$	$V_{CE} = 2\text{V}, I_C = 2\text{A}$	100			
	$h_{FE(5)}$	$V_{CE} = 2\text{V}, I_C = 6\text{A}$		40		
Collector-emitter saturation voltage (Note 2)	$V_{CE(sat)1}$	$I_C = 0.1\text{A}, I_B = 10\text{mA}$			20	mV
	$V_{CE(sat)2}$	$I_C = 1\text{A}, I_B = 10\text{mA}$			200	mV
	$V_{CE(sat)3}$	$I_C = 2\text{A}, I_B = 100\text{mA}$			220	mV
Base-emitter saturation voltage (Note 2)	$V_{BE(sat)}$	$I_C = 2\text{A}, I_B = 50\text{mA}$			1	V
Base-emitter on voltage (Note 2)	$V_{BE(on)}$	$I_C = 2\text{A}, V_{CE} = 2\text{V}$			1	V
Output capacitance	C_{ob}	$V_{CB} = 10\text{V}, f = 1\text{MHz}$			20	pF
Turn-on time	$t_{(on)}$	$V_{CC} = 10\text{V}, I_C = 1\text{A}$ $I_{B1} = -I_{B2} = 10\text{mA}$		170		nS
Turn-off time	$t_{(off)}$			750		nS
Transition frequency	f_T	$V_{CE} = 10\text{V}, I_C = 50\text{mA}, f = 100\text{MHz}$	100			MHz

Notes: 1. Maximum power dissipation is calculated assuming that the device is mounted on a ceramic substrate measuring 15x15x0.6mm.

2. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2.0\%$.

Rating and Characteristic Curves (FMMT619-HF)

Fig.1 - Static Characteristic

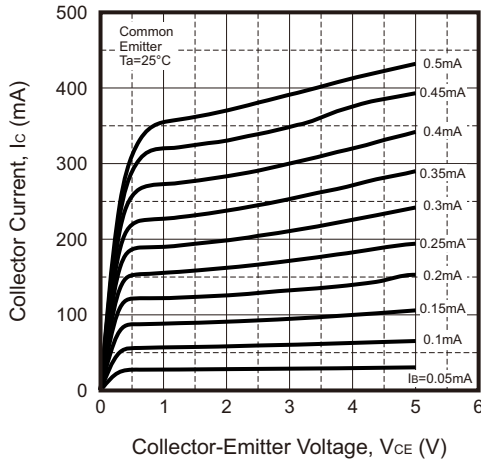


Fig.2 - $h_{FE} - I_c$

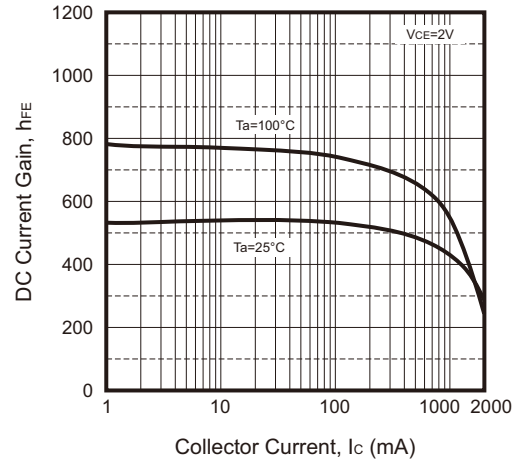


Fig.3 - $V_{BEsat} - I_c$

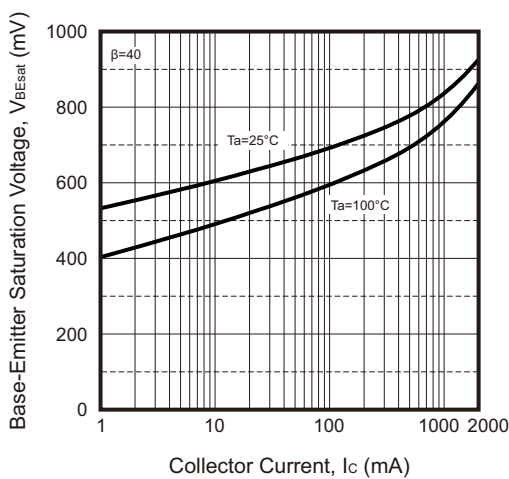


Fig.4 - $V_{CEsat} - I_c$

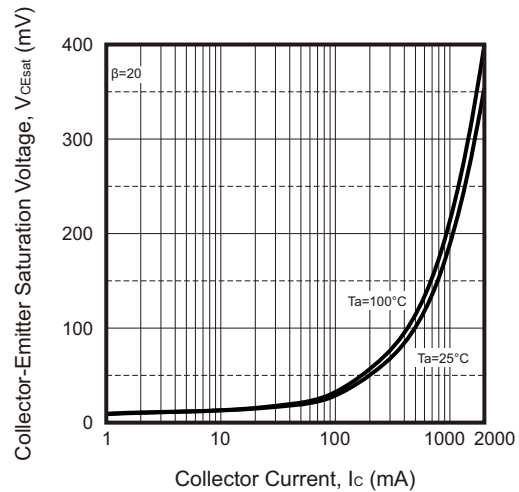


Fig.5 - $f_r - I_c$

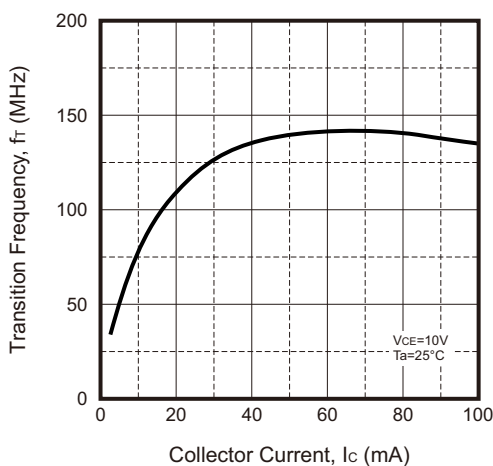
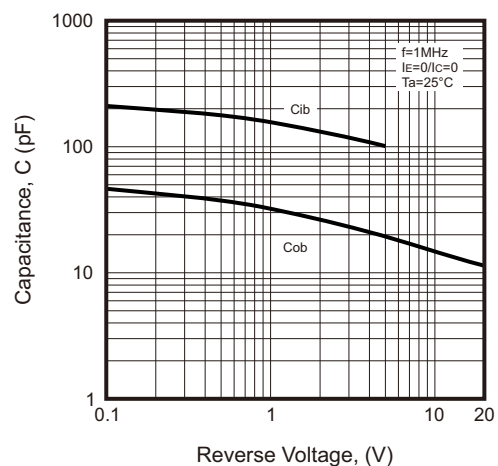


Fig.6 - $C_{ob}/C_{ib} - V_{CB}/V_{EB}$



Rating and Characteristic Curves (FMMT619-HF)

Fig.7 - $V_{BE} - I_c$

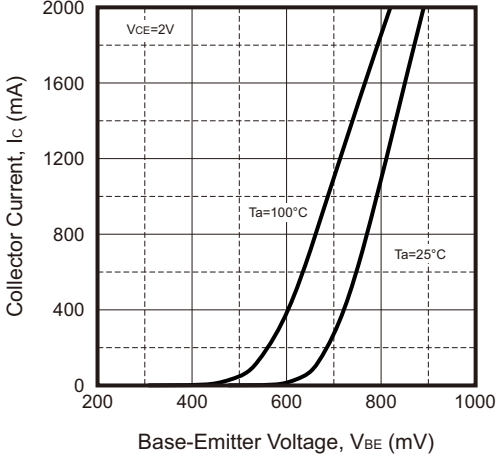
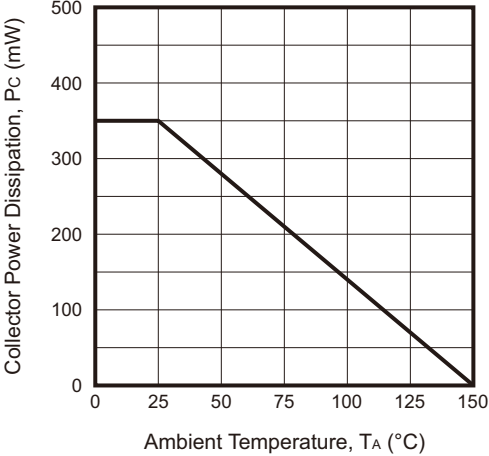
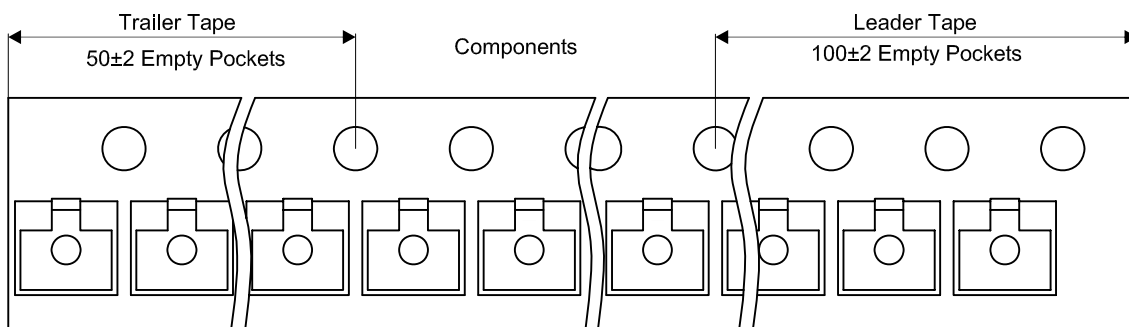
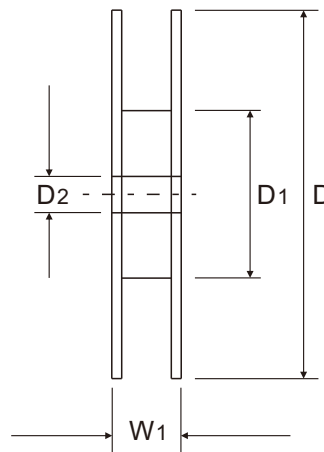
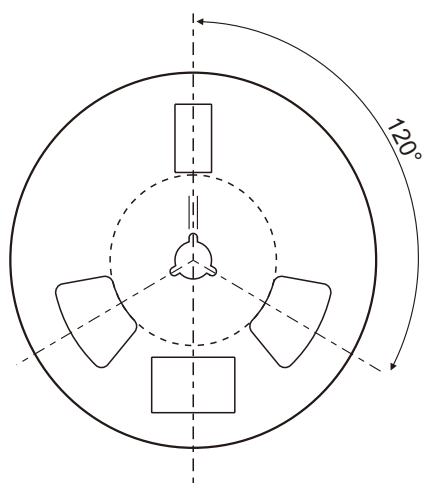
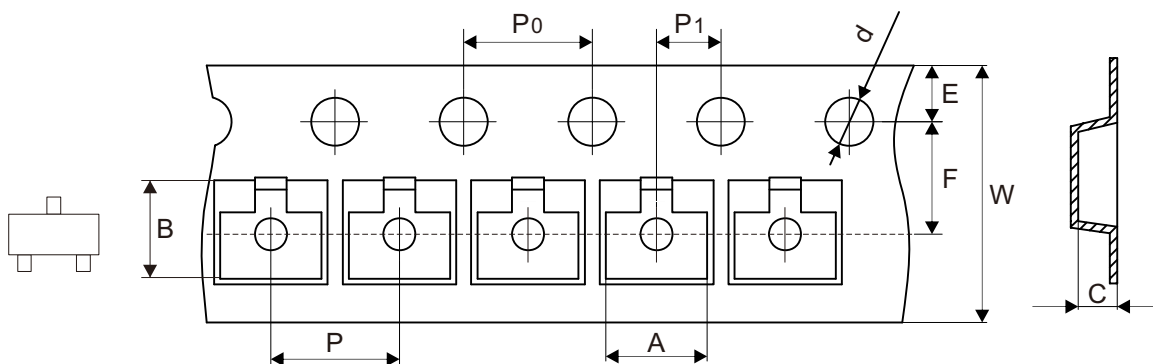


Fig.8 - $P_c - T_A$



Reel Taping Specification

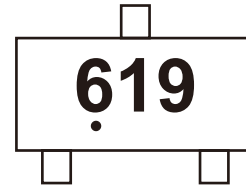


SOT-23	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	3.15 ± 0.10	2.77 ± 0.10	1.22 ± 0.10	1.50 ± 0.10	178.00 ± 2.00	54.40 ± 1.00	13.00 ± 1.00
	(inch)	0.124 ± 0.004	0.109 ± 0.004	0.048 ± 0.004	0.059 ± 0.004	7.008 ± 0.079	2.142 ± 0.039	0.512 ± 0.039

SOT-23	SYMBOL	E	F	P	P0	P1	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	8.00 + 0.30 - 0.10	12.30 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.315 + 0.012 - 0.004	0.484 ± 0.039

Marking Code

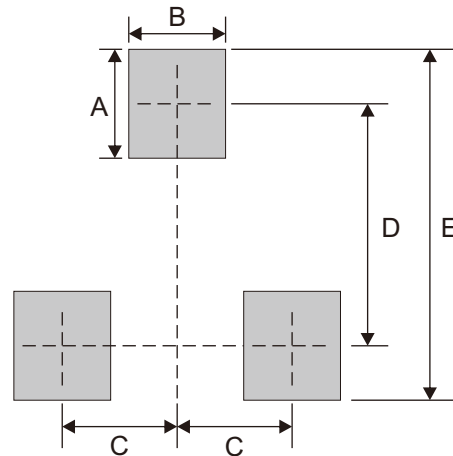
Part Number	Marking Code
FMMT619-HF	619



Solid dot = Control code

Suggested P.C.B. PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.90	0.035
B	0.80	0.031
C	0.95	0.037
D	2.00	0.079
E	2.90	0.114



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23	3,000	7